

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LCX08F, TC74LCX08FK

### Low-Voltage Quad 2-Input AND Gate with 5-V Tolerant Inputs and Outputs

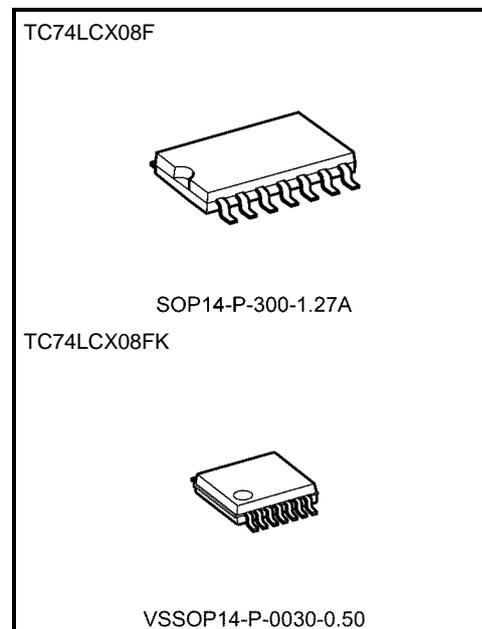
The TC74LCX08 is a high-performance CMOS 2-input AND gate. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V)  $V_{CC}$  applications, but it could be used to interface to 5-V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

### Features

- Low-voltage operation:  $V_{CC} = 2.0$  to  $3.6$  V
- High-speed operation:  $t_{pd} = 5.5$  ns (max) ( $V_{CC} = 3.0$  to  $3.6$  V)
- Output current:  $|I_{OH}|/I_{OL} = 24$  mA (min) ( $V_{CC} = 3.0$  V)
- Available in JEITA SOP, VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 08 type



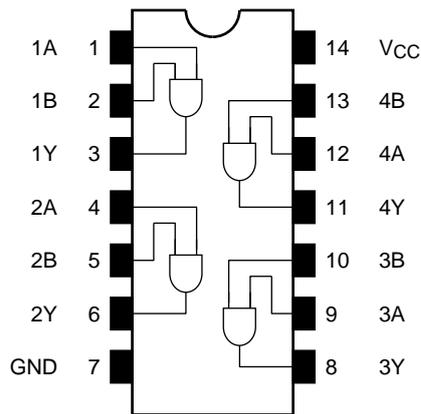
Weight

SOP14-P-300-1.27A : 0.18 g ( typ.)

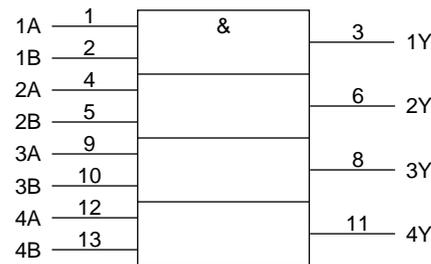
VSSOP14-P-0030-0.50 : 0.02 g ( typ.)

Start of commercial production  
1994-10

### Pin Assignment (top view)



### IEC Logic Symbol



### Truth Table

Inputs		Outputs
A	B	Y
L	L	L
L	H	L
H	L	L
H	H	H

### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to 7.0 (Note 2)	V
		-0.5 to V <sub>CC</sub> + 0.5 (Note 3)	
Input diode current	I <sub>IK</sub>	-50	mA
Output diode current	I <sub>OK</sub>	±50 (Note 4)	mA
DC output current	I <sub>OUT</sub>	±50	mA
Power dissipation	P <sub>D</sub>	180	mW
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: V<sub>CC</sub> = 0 V

Note 3: High or low state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 4: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>

### Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power Supply voltage	V <sub>CC</sub>	2.0 to 3.6	V
		1.5 to 3.6 (Note 2)	
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to 5.5 (Note 3)	V
		0 to V <sub>CC</sub> (Note 4)	
Output current	I <sub>OH</sub> /I <sub>OL</sub>	±24 (Note 5)	mA
		±12 (Note 6)	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.  
Unused inputs must be tied to either V<sub>CC</sub> or GND.

Note 2: Data retention only

Note 3: V<sub>CC</sub> = 0 V

Note 4: High or low state

Note 5: V<sub>CC</sub> = 3.0 to 3.6 V

Note 6: V<sub>CC</sub> = 2.7 to 3.0 V

Note 7: V<sub>IN</sub> = 0.8 to 2.0 V, V<sub>CC</sub> = 3.0 V

### Electrical Characteristics

#### DC Characteristics (T<sub>a</sub> = -40 to 85°C)

Characteristics		Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>	—		2.7 to 3.6	2.0	—	V
	L-level	V <sub>IL</sub>	—		2.7 to 3.6	—	0.8	
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -12 mA	2.7	2.2	—	
				I <sub>OH</sub> = -18 mA	3.0	2.4	—	
				I <sub>OH</sub> = -24 mA	3.0	2.2	—	
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7 to 3.6	—	0.2	
				I <sub>OL</sub> = 12 mA	2.7	—	0.4	
				I <sub>OL</sub> = 16 mA	3.0	—	0.4	
				I <sub>OL</sub> = 24 mA	3.0	—	0.55	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		2.7 to 3.6	—	±5.0	μA
Power-off leakage current		I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5 V		0	—	10.0	μA
Quiescent supply current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	—	10.0	μA
			V <sub>IN</sub> = 3.6 to 5.5 V		2.7 to 3.6	—	±10.0	
Increase in I <sub>CC</sub> per input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V (per 1 input)		2.7 to 3.6	—	500	

### AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	—	6.2	ns
	t <sub>pHL</sub>		3.3 ± 0.3	1.5	5.5	
Output to output skew	t <sub>osLH</sub>	(Note)	2.7	—	—	ns
	t <sub>osHL</sub>		3.3 ± 0.3	—	1.0	

Note: Parameter guaranteed by design.  
 (t<sub>osLH</sub> = |t<sub>pLHm</sub> - t<sub>pLHn</sub>|, t<sub>osHL</sub> = |t<sub>pHLm</sub> - t<sub>pHLn</sub>|)

### Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.5 ns, CL = 50 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Typ.	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V	3.3	0.8	V

### Capacitive Characteristics (Ta = 25°C)

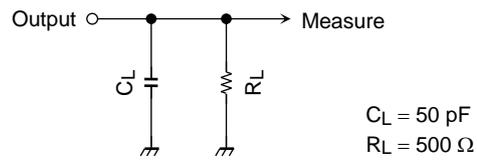
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Typ.	Unit
Input capacitance	C <sub>IN</sub>	—	3.3	7	pF
Output capacitance	C <sub>OUT</sub>	—	0	8	pF
Power dissipation capacitance	CPD	f <sub>IN</sub> = 10 MHz	(Note) 3.3	25	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

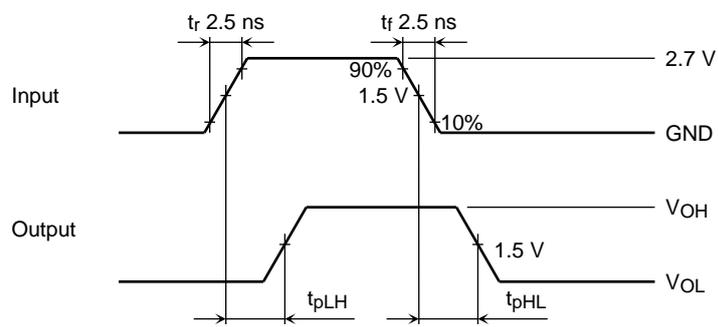
$$I_{CC} (opr) = CPD \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

### AC Test Circuit



**Figure 1**

### AC Waveform

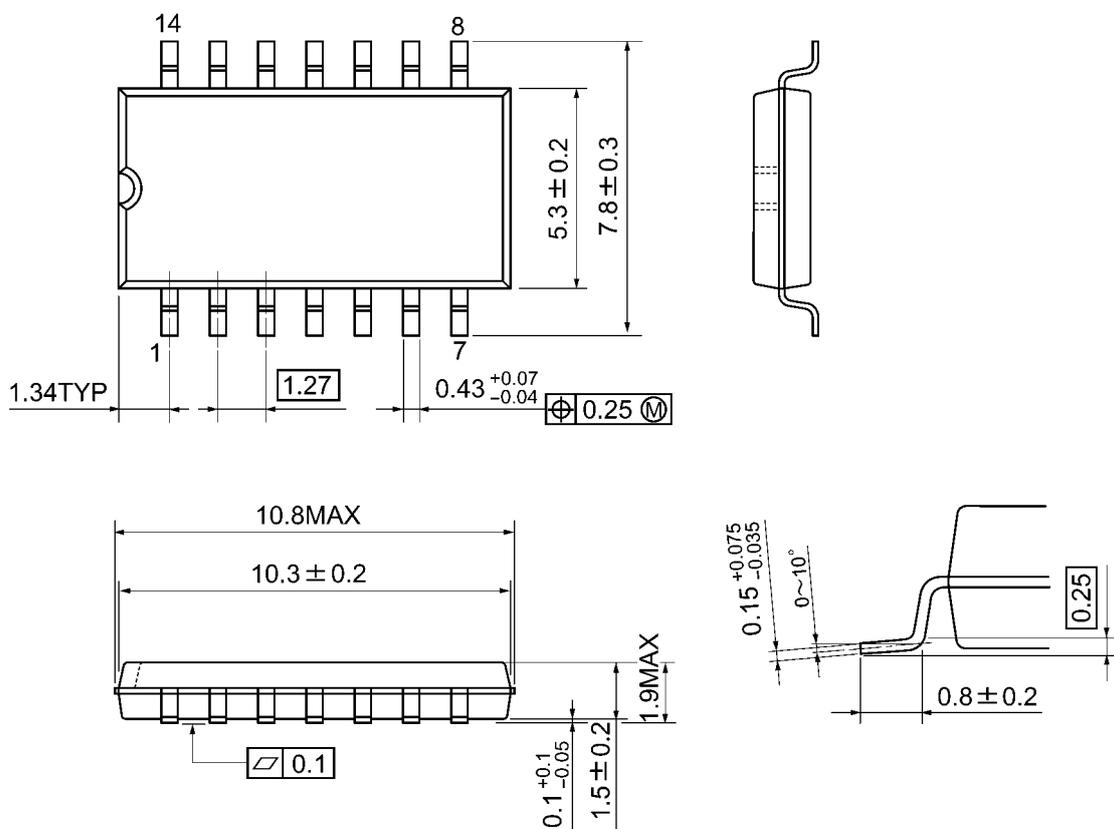


**Figure 2**  $t_{pLH}$ ,  $t_{pHL}$

### Package Dimensions

SOP14-P-300-1.27A

Unit: mm

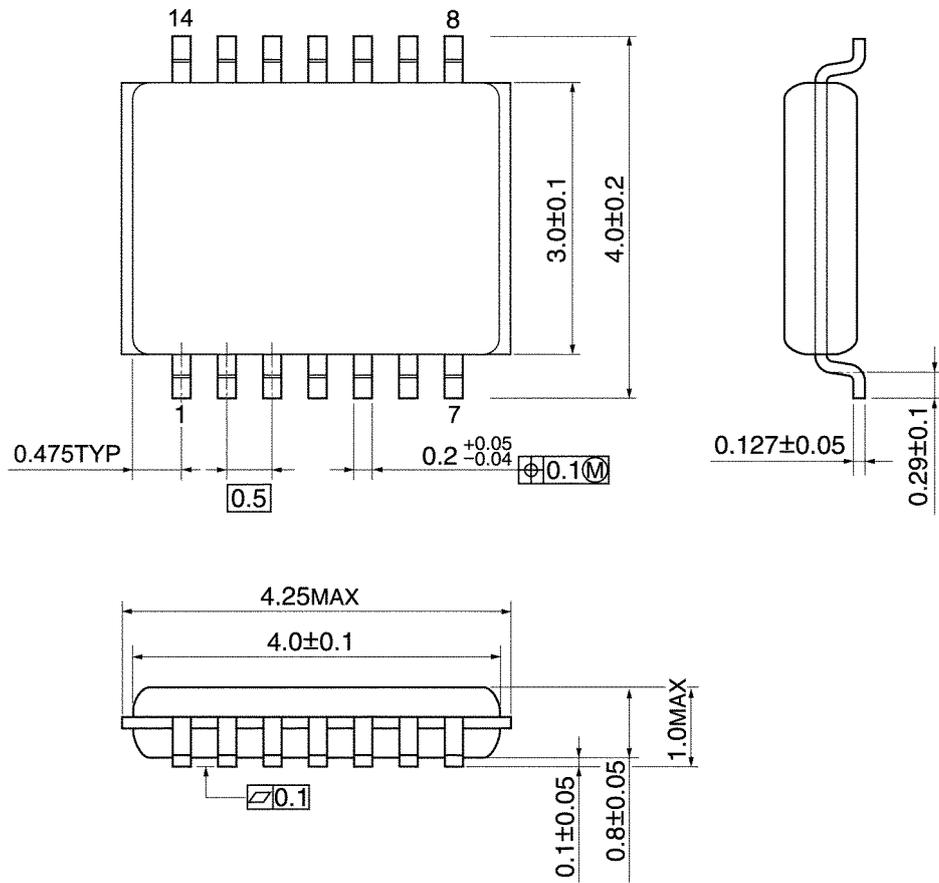


Weight: 0.18 g (typ.)

### Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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